# 74AUP1G132

# Low-power 2-input NAND Schmitt trigger

Rev. 6 — 1 May 2019

**Product data sheet** 

### 1. General description

The 74AUP1G132 provides the single 2-input NAND Schmitt trigger function which accept standard input signals. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage  $V_{T+}$  and the negative voltage  $V_{T-}$  is defined as the input hysteresis voltage  $V_{H-}$ .

#### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

# 3. Applications

- · Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator.



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# 4. Ordering information

**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G132GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74AUP1G132GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G132GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891
74AUP1G132GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G132GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202
74AUP1G132GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.35 mm	SOT1226

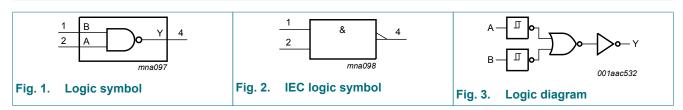
# 5. Marking

Table 2. Marking

Type number	Marking code [1]
74AUP1G132GW	аЕ
74AUP1G132GM	аЕ
74AUP1G132GF	аЕ
74AUP1G132GN	аЕ
74AUP1G132GS	аЕ
74AUP1G132GX	аЕ

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

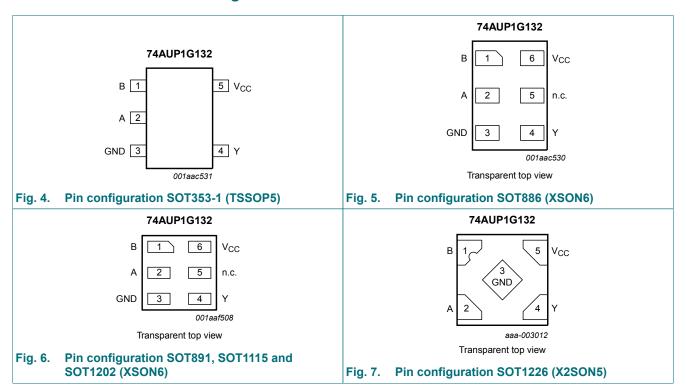
# 6. Functional diagram



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# 7. Pinning information

### 7.1. Pinning



### 7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description	
	TSSOP5 and X2SON5	XSON6	
В	1	1	data input
A	2	2	data input
GND	3	3	ground (0 V)
Υ	4	4	data output
n.c.	-	5	not connected
V <sub>CC</sub>	5	6	supply voltage

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## 8. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input	Output	
A	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

# 9. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
V <sub>O</sub>	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I <sub>O</sub>	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>1]</sup> The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C

<sup>[2]</sup> For TSSOP5 packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.

For XSON6 and X2SON5 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

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## 11. Static characteristics

**Table 7. Static characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C					
V <sub>OH</sub>	HIGH-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	$I_{\rm O}$ = -20 $\mu$ A; $V_{\rm CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V} $ [1]	-	-	40	μΑ
Cı	input capacitance	$V_I = GND \text{ or } V_{CC}$ ; $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	1.1	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C				'	
V <sub>OH</sub>	HIGH-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V

### **Low-power 2-input NAND Schmitt trigger**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	LOW-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	μΑ
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μΑ
$\Delta I_{CC}$	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μA
T <sub>amb</sub> = -4	40 °C to +125 °C					
V <sub>OH</sub>	HIGH-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	$I_{\rm O}$ = -20 $\mu$ A; $V_{\rm CC}$ = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.77	-	-	V
		$I_{O}$ = -3.1 mA; $V_{CC}$ = 2.3 V	1.67	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.40	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{T+}$ or $V_{T-}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μA
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1.4	μA
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μΑ

<sup>[1]</sup> One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

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Low-power 2-input NAND Schmitt trigger

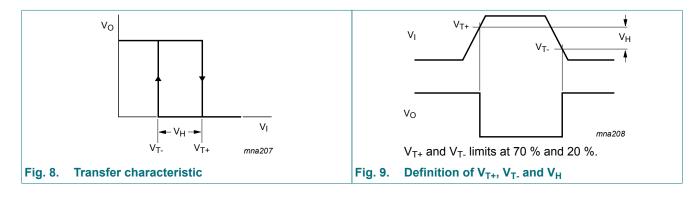
## 11.1. Transfer characteristics

**Table 8. Transfer characteristics** 

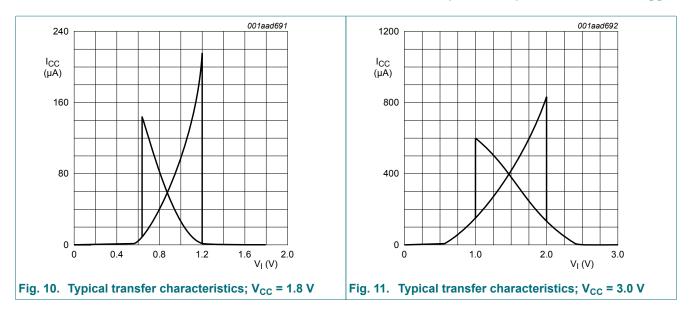
Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 13.

Symbol	Parameter	Conditions	conditions 25 °C				°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>T+</sub>	positive-going	see Fig. 8 and Fig. 9								
	threshold voltage	V <sub>CC</sub> = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	Voltage	V <sub>CC</sub> = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V <sub>CC</sub> = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
$V_{T-}$	negative-going	see Fig. 8 and Fig. 9								
	threshold voltage	V <sub>CC</sub> = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
		V <sub>CC</sub> = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V <sub>CC</sub> = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
V <sub>H</sub>	hysteresis voltage	(V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 8</u> , <u>Fig. 9</u> , <u>Fig. 10</u> and <u>Fig. 11</u>								
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V <sub>CC</sub> = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

### 11.2. Waveforms transfer characteristics



### Low-power 2-input NAND Schmitt trigger



# 12. Dynamic characteristics

**Table 9. Dynamic characteristics** 

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 13.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F									
t <sub>pd</sub>	propagation	A or B to Y; see Fig. 12 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	22.5	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.6	6.3	13.4	2.4	15.1	2.4	16.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	4.6	8.2	1.9	9.7	1.9	10.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.9	1.7	8.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	3.2	5.3	1.5	6.2	1.5	6.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.6	2.9	4.7	1.4	5.6	1.4	6.2	ns
C <sub>L</sub> = 10	pF									
t <sub>pd</sub>	propagation delay	A or B to Y; see <u>Fig. 12</u> [2]								
		V <sub>CC</sub> = 0.8 V	-	26.1	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.0	7.2	15.4	2.7	17.3	2.7	19.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.5	5.2	9.3	2.2	11.0	2.2	12.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	4.5	7.5	2.0	9.0	2.0	9.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.8	6.1	1.8	7.2	1.8	7.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.5	5.5	1.8	6.5	1.8	7.2	ns
C <sub>L</sub> = 15	pF						,			
t <sub>pd</sub>	propagation	A or B to Y; see <u>Fig. 12</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	29.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.3	8.0	17.2	3.0	19.4	3.0	21.3	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.8	5.8	10.4	2.5	12.3	2.5	13.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	5.0	8.3	2.3	10.0	2.3	11.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.3	4.2	6.7	2.1	7.9	2.1	8.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.0	ns

### Low-power 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation	A or B to Y; see Fig. 12 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	39.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	3.8	27.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	3.2	17.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	2.9	14.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	2.7	11.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	2.7	10.1	ns
$C_L = 5 p$	F, 10 pF, 15 pF	and 30 pF				'				
C <sub>PD</sub>	power dissipation	$f_i$ = 1 MHz; [3] $V_I$ = GND to $V_{CC}$								
	capacitance	V <sub>CC</sub> = 0.8 V	-	2.6	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.4	-	-	-	-	-	pF

- All typical values are measured at nominal V<sub>CC</sub>.
- $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

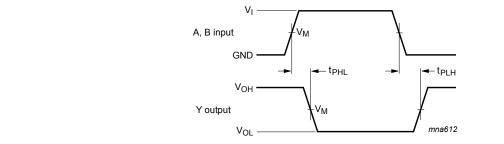
 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

#### Low-power 2-input NAND Schmitt trigger

#### 12.1. Waveforms and test circuit



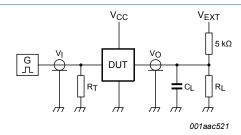
Measurement points are given in Table 10.

V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage drop that occur with the output load.

Fig. 12. The data input (A or B) to output (Y) propagation delays

Table 10. Measurement points

Supply voltage	Output	Input					
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>I</sub>	$t_r = t_f$			
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns			



Test data is given in Table 11.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 13. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>CC</sub>	C <sub>L</sub>	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	$5$ k $\Omega$ or $1$ M $\Omega$	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_L = 1 \text{ M}\Omega$ .

#### Low-power 2-input NAND Schmitt trigger

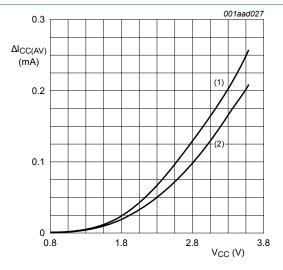
# 13. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$  where:

- P<sub>add</sub> = additional power dissipation (μW);
- f<sub>i</sub> = input frequency (MHz);
- t<sub>r</sub> = input rise time (ns); 10 % to 90 %;
- t<sub>f</sub> = input fall time (ns); 90 % to 10 %;
- ΔI<sub>CC(AV)</sub> = average additional supply current (µA).

Average  $\Delta I_{CC(AV)}$  differs with positive or negative input transitions, as shown in Fig. 14.



- (1) Positive-going edge.
- (2) Negative-going edge.

Linear change of V<sub>I</sub> between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

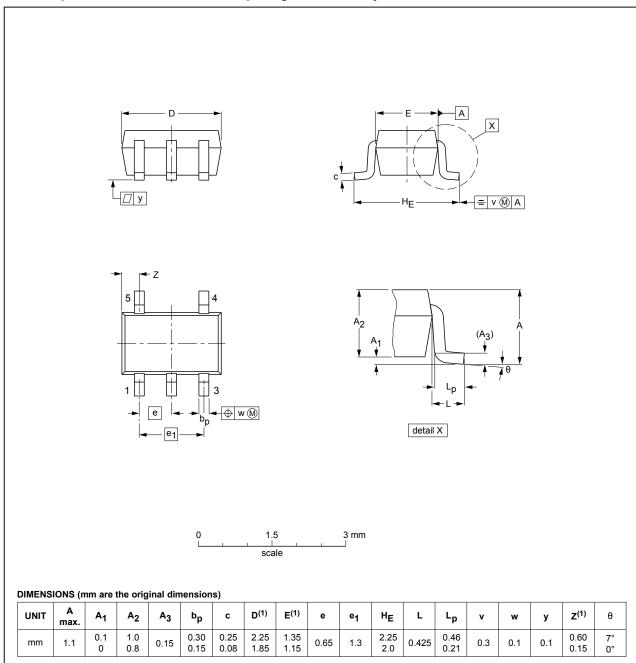
Fig. 14. Average I<sub>CC</sub> as a function of V<sub>CC</sub>

#### Low-power 2-input NAND Schmitt trigger

# 14. Package outline



SOT353-1



#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A			<del>-00-09-01</del> 03-02-19

Fig. 15. Package outline SOT353-1 (TSSOP5)

### Low-power 2-input NAND Schmitt trigger

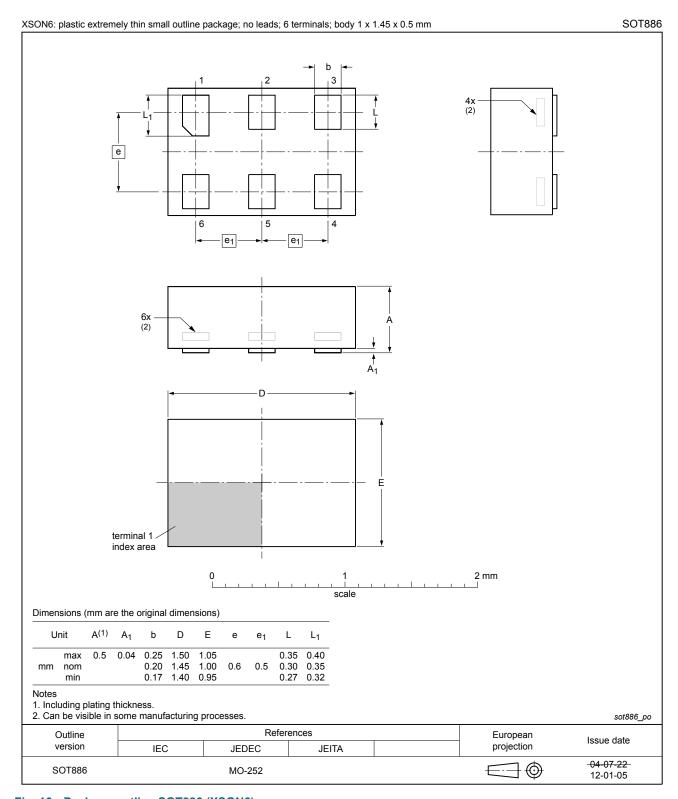


Fig. 16. Package outline SOT886 (XSON6)

#### Low-power 2-input NAND Schmitt trigger

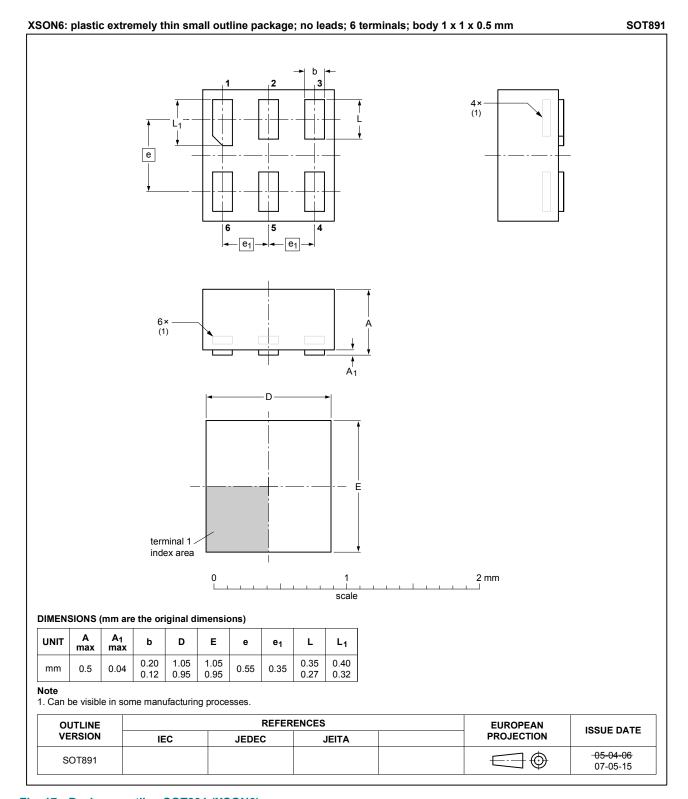


Fig. 17. Package outline SOT891 (XSON6)

### Low-power 2-input NAND Schmitt trigger

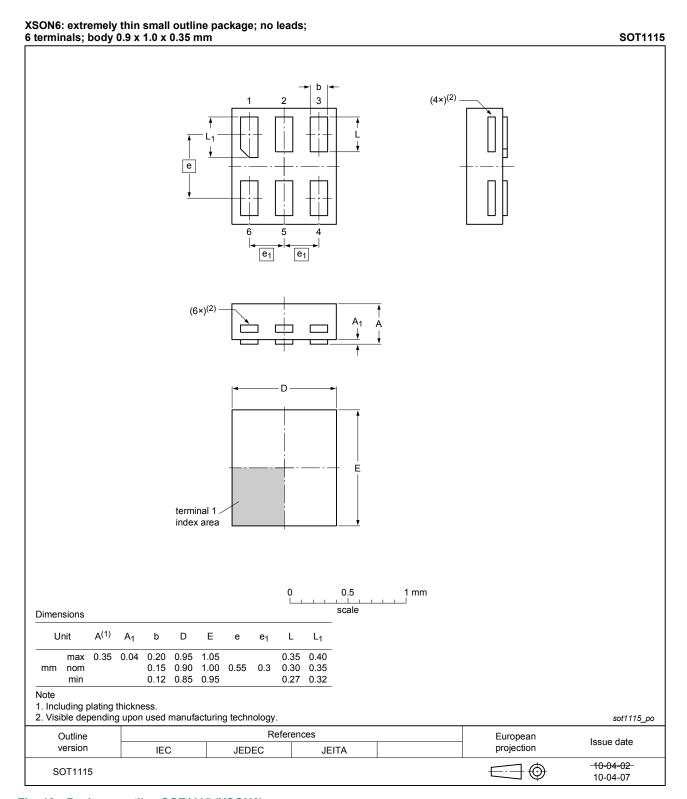


Fig. 18. Package outline SOT1115 (XSON6)

### Low-power 2-input NAND Schmitt trigger

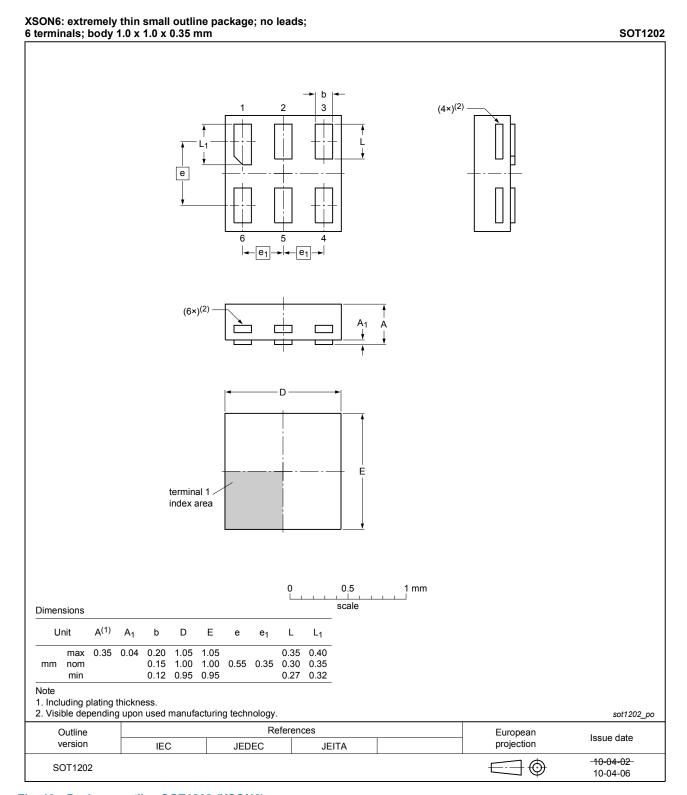


Fig. 19. Package outline SOT1202 (XSON6)

#### Low-power 2-input NAND Schmitt trigger

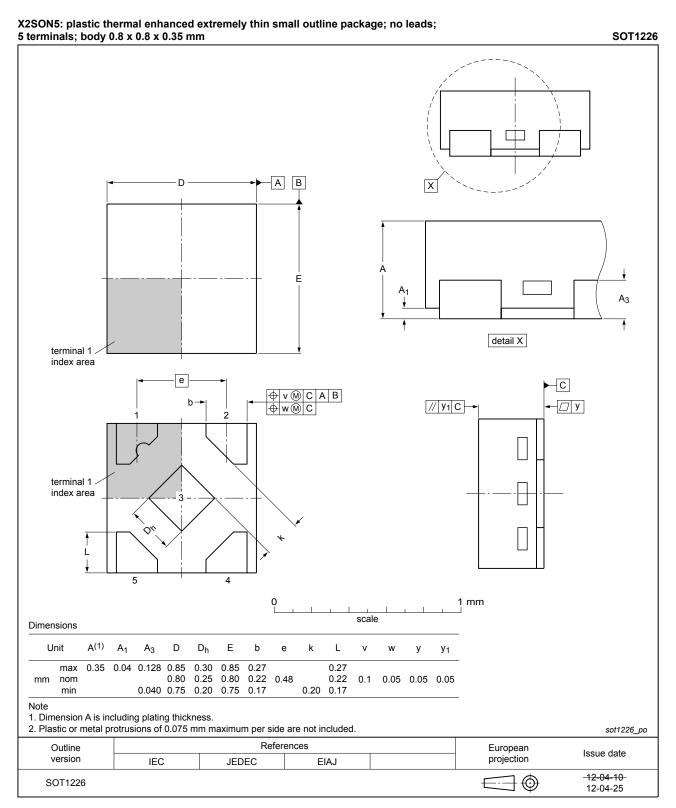


Fig. 20. Package outline SOT1226 (X2SON5)

Low-power 2-input NAND Schmitt trigger

## 15. Abbreviations

#### **Table 12. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

# 16. Revision history

#### **Table 13. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G132 v.6	20190501	Product data sheet	-	74AUP1G132 v.5
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li><u>Fig. 7</u>: Pin configuration drawing SOT1226 (X2SON5) updated.</li> </ul>			
74AUP1G132 v.5	20120629	Product data sheet	-	74AUP1G132 v.4
Modifications:	<ul> <li>Added type number 74AUP1G132GX (SOT1226)</li> <li>Package outline drawing of SOT886 (Fig. 16) modified.</li> </ul>			
74AUP1G132 v.4	20111124	Product data sheet	-	74AUP1G132 v.3
Modifications:	Legal pages	updated.		
74AUP1G132 v.3	20101029	Product data sheet	-	74AUP1G132 v.2
74AUP1G132 v.2	20090615	Product data sheet	-	74AUP1G132 v.1
74AUP1G132 v.1	20061020	Product data sheet	-	-

### Low-power 2-input NAND Schmitt trigger

## 17. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

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